# **Surface Mount Schottky Barrier Rectifiers**

1 A, 30 V - 60 V

# **SS13HE, NRVBSS13HE Series**

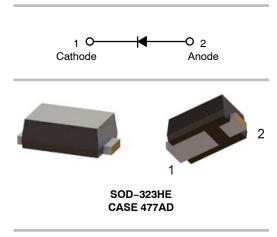
#### **Features**

- Very Low Profile Typical Height of 0.68 mm
- Low Power Loss, High Efficiency
- Moisture Sensitivity Level 1 per J–STD–020
- UL Flammability 94V-0 Classification
- RoHS Compliant / Green Molding Compound
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable



### ON Semiconductor®

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#### **ORDERING INFORMATION**

Part Number	Top Mark	Package	Shipping Method <sup>†</sup>
SS13HE	1A	SOD-323HE	3000 / Tape and Reel
SS14HE	1B	SOD-323HE	3000 / Tape and Reel
SASS14HE	1B	SOD-323HE	3000 / Tape and Reel
SS16HE	1C	SOD-323HE	3000 / Tape and Reel
NRVBSS13HE	1A	SOD-323HE	3000 / Tape and Reel
NRVBSS14HE	1B	SOD-323HE	3000 / Tape and Reel
NRVBSS16HE	1C	SOD-323HE	3000 / Tape and Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## SS13HE, NRVBSS13HE Series

**Table 1. ABSOLUTE MAXIMUM RATINGS** Values are at  $T_A = 25$ °C unless otherwise noted.

		Value			
Symbol	Parameter	SS13HE	SS14HE, SASS14HE	SS16HE	Unit
$V_{RRM}$	Maximum Repetitive Peak Reverse Voltage	30	40	60	V
$V_{R}$	Reverse Voltage	30	40	60	V
I <sub>F(AV)</sub>	Maximum Average Forward Rectified Current		1		
I <sub>FSM</sub>	Peak Forward Surge Current: 8.3 ms Single Half Sine-Wave Superimposed on Rated Load		25		Α
TJ	Operating Junction Temperature Range	-55 to +150		°C	
T <sub>STG</sub>	Storage Temperature Range		−55 to +150		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 2. THERMAL CHARACTERISTICS (Note 1) Values are at  $T_A = 25^{\circ}C$  unless otherwise noted.

Symbol	Parameter	Value	Unit
$\Psi_{\sf JL}$	Junction-to-Lead Thermal Resistance Thermocouple Soldered to Cathode	21	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance (Note 1)	199	°C/W

<sup>1.</sup> Per JESD51-3 Recommended Thermal Test Board. Device mounted on FR-4 PCB, board size = 76.2 mm x 114.3 mm

Table 3. ELECTRICAL CHARACTERISTICS Values are at  $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>F</sub>	Instantaneous Forward	I <sub>F</sub> = 0.5 A, T <sub>J</sub> = 25°C	SS13HE,		0.41		V
	Voltage (Note 2)	I <sub>F</sub> = 0.5 A, T <sub>J</sub> = 125°C	SS14HE, SASS14HE		0.31		.68
		I <sub>F</sub> = 1.0 A, T <sub>J</sub> = 25°C			0.46	0.55	
		I <sub>F</sub> = 1.0 A, T <sub>J</sub> = 125°C			0.40	0.50	
		$I_F = 0.5 \text{ A}, T_J = 25^{\circ}\text{C}$	SS16HE		0.51		
		I <sub>F</sub> = 0.5 A, T <sub>J</sub> = 125°C			0.45		
		I <sub>F</sub> = 1.0 A, T <sub>J</sub> = 25°C			0.61	0.68	
		I <sub>F</sub> = 1.0 A, T <sub>J</sub> = 125°C			0.54	0.60	
I <sub>R</sub>	Reverse Current at Rated V <sub>R</sub>	T <sub>J</sub> = 25°C	SS13HE, SS14HE,		5.0	50	μΑ
		T <sub>J</sub> = 125°C	SASS14HE,		3.0	10	mA
		T <sub>J</sub> = 25°C	SS16HE		2.0	50	μΑ
		T <sub>J</sub> = 125°C			1.5	10	mA
T <sub>rr</sub>	Reverse Recovery Time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$	SS13HE, SS14HE, SASS14HE		5.6		ns
			SS16HE		8.3		
СЈ	Junction Capacitance	V <sub>R</sub> = 4.0 V, f = 1 MHz	SS13HE, SS14HE, SASS14HE		55		pF
			SS16HE		43		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse test with PW = 300  $\mu$ s, 1% duty cycle

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#### TYPICAL PERFORMANCE CHARACTERISTICS

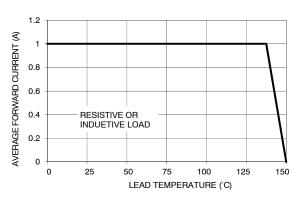


Figure 1. Forward Current Derating Curve

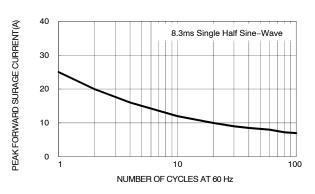


Figure 2. Maximum Non-Repetitive Forward Surge Current

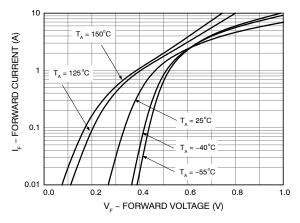


Figure 3. Typical Forward Characteristics – SS13HE / SS14HE

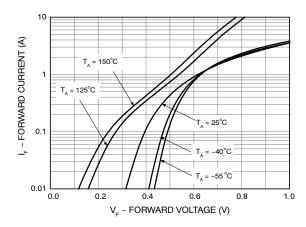


Figure 4. Typical Forward Characteristics – SS16HE

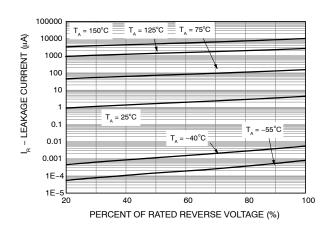


Figure 5. Typical Reverse Characteristics – SS13HE / SS14HE

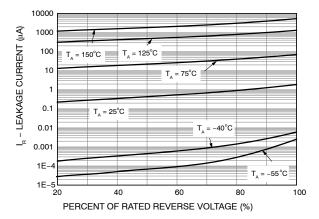


Figure 6. Typical Reverse Characteristics – SS16HE

# SS13HE, NRVBSS13HE Series

# TYPICAL PERFORMANCE CHARACTERISTICS

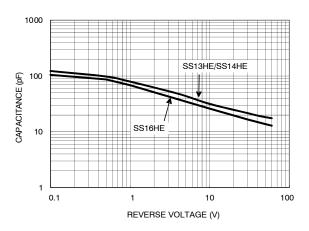
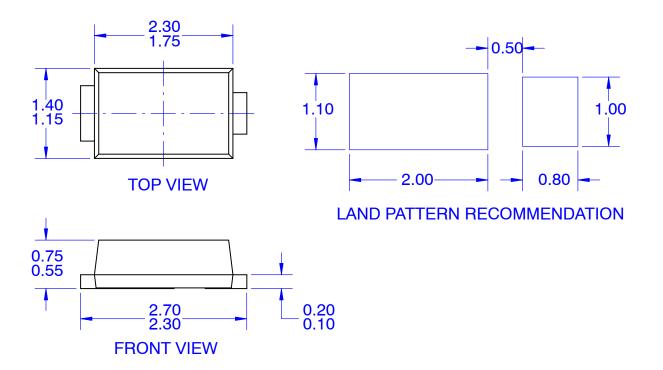


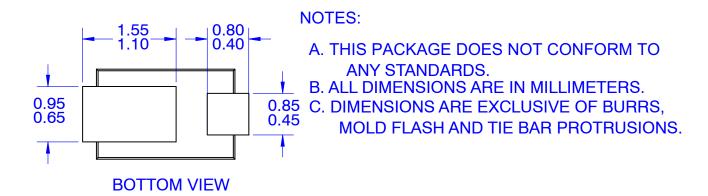
Figure 7. Typical Junction Capacitance



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